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LP5996 Dual Linear Regulator with 300mA and 150mA Outputs **General Description Key Specifications**

The LP5996 is a dual low dropout regulator. The first regulator can source 150mA, while the second is capable of sourcing 300mA.

The LP5996 provides 1.5% accuracy requiring an ultra low quiescent current of 35µA. Separate enable pins allow each output of the LP5996 to be shut down, drawing virtually zero current.

The LP5996 is designed to be stable with small footprint ceramic capacitors down to 1µF.

The LP5996 is available in fixed output voltages and comes in a 10 pin, 3mm x 3mm, LLP package. .

Features

- 2 LDO Outputs with Independent Enable
- 1.5% Accuracy at Room Temperature, 3% over Temperature
- Thermal Shutdown Protection
- Stable with Ceramic Capacitors

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- Input Voltage Range
- Low Dropout Voltage ■ Ultra-Low I_O (enabled)
- Virtually Zero I_Q (disabled)

Package

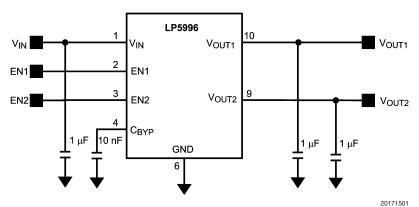
All available in Lead Free option.

10 pin LLP 3mm x 3mm For other package options contact your NSC sales office.

Applications

- Cellular Handsets
- PDA's
- Wireless Network Adaptors

Typical Application Circuit



DS201715

November 2006

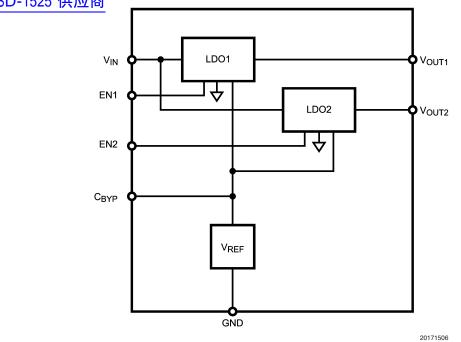
2.0V to 6.0V

35µA

<10nA

210mV at 300mA

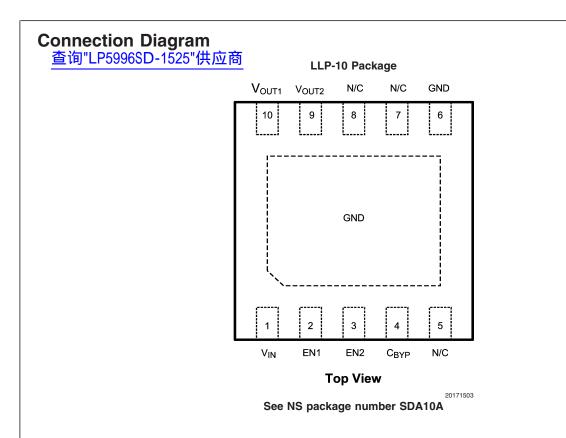
8 **Functional Block Diagram** 雪询"LP5996SD-1525"供应商



Pin Descriptions

LLP-10 Package

		-
Pin No	Symbol	Name and Function
1	V _{IN}	Voltage Supply Input. Connect a 1µF capacitor between this
		pin and GND.
2	EN1	Enable Input to Regulator 1. Active high input.
		High = On. Low = OFF.
3	EN2	Enable Input to Regulator 2. Active high input.
		High = On. Low = OFF.
4	C _{BYP}	Internal Voltage Reference Bypass. Connect a 10nF capacitor
		from this pin to GND to reduce noise and improve line
		transient and PSRR.
		This pin may be left open.
5	N/C	No Connection. Do not connect to any other pin.
6	GND	Common Ground pin. Connect externally to exposed pad.
7	N/C	No Connection. Do not connect to any other pin.
8	N/C	No Connection. Do not connect to any other pin.
9	V _{OUT2}	Output of Regulator 2. 300mA maximum current output.
		Connect a 1µF capacitor between this pin to GND.
10	V _{OUT1}	Output of Regulator 1. 150mA maximum current output.
		Connect a 1µF capacitor between this pin to GND.
Pad	GND	Common Ground. Connect to Pin 6.



LP5996

Output Voltage (V)	Order Number	Spec	Package Marking	Supplied As
0.8 / 3.3	LP5996SD-0833	NOPB	L176B	1000 Units, Tape-and-Reel
0.07 0.0	LP5996SD-0033	NOPB	LIVOD	4500 Units, Tape-and-Ree
-	LP5996SD-0833			1000 Units, Tape-and-Ree
-	LP5996SD-0033			4500 Units, Tape-and-Ree
1.5 / 2.5	LP5996SD-1525	NOPB	L177B	1000 Units, Tape-and-Ree
1.5 / 2.5	LP5996SDX-1525	NOPB	LITTD	4500 Units, Tape-and-Ree
	LP5996SD-1525	NOFB		1000 Units, Tape-and-Ree
_	LP5996SDX-1525			4500 Units, Tape-and-Ree
2.8 / 2.8	LP5996SD-2828	NOPB	L180B	1000 Units, Tape-and-Ree
2.0 / 2.0	LP5996SDX-2828	NOPB	LIOOD	4500 Units, Tape-and-Ree
	LP5996SD-2828			1000 Units, Tape-and-Ree
	LP5996SDX-2828			4500 Units, Tape-and-Ree
3.0 / 3.0	LP5996SD-3030	NOPB	L181B	1000 Units, Tape-and-Ree
5.07 5.0	LP5996SDX-3030	NOPB	LIGID	4500 Units, Tape-and-Ree
-	LP5996SD-3030	NOFB		1000 Units, Tape-and-Ree
-	LP5996SDX-3030			4500 Units, Tape-and-Ree
3.0 / 3.3	LP5996SD-3033	NOPB	L179B	1000 Units, Tape-and-Ree
5.07 5.5	LP5996SDX3033	NOPB	L179D	4500 Units, Tape-and-Ree
_	LP5996SD-3033	NOFB		1000 Units, Tape-and-Ree
	LP5996SDX3033			4500 Units, Tape-and-Ree
3.3 / 0.8	LP5996SD-3308	NOPB	L205B	1000 Units, Tape-and-Ree
3.370.0	LP5996SDX-3308	NOPB	L203B	4500 Units, Tape-and-Ree
_	LP5996SD-3308	NOFD		1000 Units, Tape-and-Ree
-	LP5996SDX-3308			4500 Units, Tape-and-Ree
3.3 / 3.3	LP5996SDX-3308	NOPB	L182B	1000 Units, Tape-and-Ree
3.3 / 3.3	LP5996SDX-3333	NOPB	L102D	4500 Units, Tape-and-Ree
	LP5996SDX-3333			1000 Units, Tape-and-Ree
	LP5996SDX-3333			4500 Units, Tape-and-Re

Absolute Maximum Ratings (N贏എ"与P5996SD-1525"供应商

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

-0.3V to 6.5V
(_{IN} + 0.3V) with
6.5V (max)
150°C
235°C
-65°C to 150°C

ESD Rating(Note 5) Human Body Model Machine Model

Operating Ratings(Notes 1, 2)

Input Voltage	2.0V to 6.0V
EN1, EN2 Voltage	0 to $(V_{IN} + 0.3V)$ to
	6.0V (max)
Junction Temperature	-40°C to 125°C
Ambient Temperature T _A Range	-40°C to 85°C
(Note 6)	

Thermal Properties(Note 1)

Junction To Ambient Thermal Resistance(Note 7) θ_{IA}LLP-10 Package

55°C/W

Electrical Characteristics (Notes 2, 8)

Unless otherwise noted, $V_{EN} = 950$ mV, $V_{IN} = V_{OUT} + 1.0$ V, or 2.0V, whichever is higher, where V_{OUT} is the higher of V_{OUT1} and V_{OUT2} . $C_{IN} = 1 \ \mu$ F, $I_{OUT} = 1 \ m$ A, $C_{OUT1} = C_{OUT2} = 1.0 \mu$ F. Typical values and limits appearing in normal type apply for $T_A = 25$ °C. Limits appearing in **boldface** type apply over the full junction temperature range for operation, -40 to +125°C.

Cumhal	Parameter	Conditions		Tun	Limit		Units
Symbol	Parameter		onations	Тур	Min	Max	Units
V _{IN}	Input Voltage	(Note 9)			2	6	V
ΔV_{OUT}	Output Voltage Tolerance	I _{OUT} = 1mA	$1.5V < V_{OUT} \le 3.3V$		-2.5 - 3.75	+2.5 +3.75	
			$V_{OUT} \le 1.5V$		-2.75 - 4	+2.75 +4	%
	Line Regulation Error	$V_{IN} = (V_{OUT(NC)})$	_{DM)} + 1.0V) to 6.0V	0.03		0.3	%/V
	Load Regulation Error	I _{OUT} = 1mA to (LDO 1)		85		155	
		$I_{OUT} = 1 \text{mA to}$ (LDO 2)	300mA	26		85	μV/mA
V _{DO}	Dropout Voltage (Note 10)	I _{OUT} = 1mA to (LDO 1)	150mA	110		220	mV
		I _{OUT} = 1mA to (LDO 2)	300mA	210		550	
l _q	Quiescent Current	LDO 1 ON, LD		35		100	
		LDO 1 ON, LD I _{OUT1} = 150mA		45		110	
		LDO 1 OFF, L I _{OUT2} = 300mA	I	45		110	μA
	LDO 1 ON, LDC I _{OUT1} = 150mA,			70		170	
		$V_{EN1} = V_{EN2} =$	= 0.4V	0.5		10	nA
I _{sc}	Short Circuit Current Limit	LDO 1		420		750	mA
		LDO 2		550		840	
I _{OUT}	Maximum Output Current	LDO 1			150		mA
		LDO 2			300		

LP5996

2.0kV

200V

 Bit
 Electrical Characteristics
 (Notes 2, 8)
 (Continued)

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Cumhal	Deveneter	0.0	n dition o	Turn	Lir	nit	Linite
Symbol	Parameter	Co	nditions	Тур	Min	Max	Units
PSRR	Power Supply Rejection Ratio (Note 11)	$f = 1 kHz, I_{OUT}$ = 1mA to	LDO1	58			
		150mA С _{вур} = 10nF	LDO2	70			
		$f = 20kHz, I_{OUT}$ = 1mA to	LDO1	45			dB
		150mA С _{вур} = 10nF	LDO2	60			<u> </u>
e _n	Output noise Voltage (Note 11)	BW = 10Hz to	V _{OUT} = 0.8V	36			
		100kHz C _{BYP} = 10nF	V _{OUT} = 3.3V	75			μV _{RMS}
T _{SHUTDOWN}	Thermal Shutdown	Temperature		160			°C
		Hysteresis		20			
Enable Cont	rol Characteristics						•
I _{EN}	Input Current at V _{EN1} or V _{EN2}	$V_{EN} = 0.0V$		0.005		0.1	
		$V_{EN} = 6V$		2		5	- μΑ
V _{IL}	Low Input Threshold					0.4	V
V _{IH}	High Input Threshold				0.95		V
Timing Char	acteristics			•			
T _{ON}	Turn On Time (Note 11)	To 95% Level $C_{BYP} = 10nF$		300			μs
Transient Response	Line Transient Response ΙδV _{OUT} Ι (Note 11)	$T_{rise} = T_{fall} = 10 \mu s$ $\delta V_{IN} = 1 V C_{BYP} = 10 n F$		20			
	Load Transient Response ΙδV _{Ουτ} Ι (Note 11)	T _{rise} = T _{fall} = 1µs	LDO 1 $I_{OUT} = 1mA$ to 150mA	175			mV (pk - pk
			LDO 2 $I_{OUT} = 1mA$ to 300mA	150			

Note 1: Absolute Maximum Ratings are limits beyond which damage can occur. Operating Ratings are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed performance limits. For guaranteed performance limits and associated test conditions, see the Electrical Characteristics tables

Note 2: All Voltages are with respect to the potential at the GND pin.

Note 3: For detailed soldering specifications and information, please refer to National Semiconductor Application Note AN-1187, Leadless Leadframe Package. Note 4: Internal thermal shutdown circuitry protects the device from permanent damage.

Note 5: The human body model is 100pF discharged through a 1.5kΩ resistor into each pin. The machine model is a 200pF capacitor discharged directly into each pin.

Note 6: The maximum ambient temperature ($T_{A(max)}$) is dependant on the maximum operating junction temperature ($T_{J(max-op)} = 125^{\circ}C$), the maximum power dissipation of the device in the application ($P_{D(max)}$), and the junction to ambient thermal resistance of the part/package in the application (θ_{JA}), as given by the following equation: $T_{A(max)} = T_{J(max-op)} - (\theta_{JA} \times P_{D(max)})$.

Note 7: Junction to ambient thermal resistance is dependant on the application and board layout. In applications where high maximum power dissipation is possible, special care must be paid to thermal dissipation issues in board design.

Note 8: Min Max limits are guaranteed by design, test or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.

Note 9: V_{IN(MIN)} = V_{OUT(NOM)} + 0.5V, or 2.0V, whichever is higher.

Note 10: Dropout voltage is voltage difference between input and output at which the output voltage drops to 100mV below its nominal value. This parameter only for output voltages above 2.0V

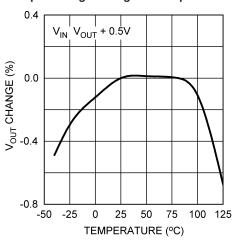
Note 11: This electrical specification is guaranteed by design.

	LP5996SD-1525"供应商				mit	
Symbol	Parameter	Conditions	Nom	Min	Max	Units
JT	Output Capacitance	Capacitance (Note 12)	1.0	0.7		μF
		ESR		5	500	mΩ
	J can also be used. (See capacitor sec					



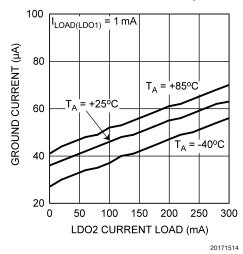
86 Typical Performance Characteristics. Unless otherwise specified, C_{IN} = 1.0μF Ceramic, C_{OUT1} = ⑤ 间"L@50969Dμff交路4供应商 = 10nF, V_{IN} = V_{OUT2(NOM)} + 1.0V, T_A = 25°C, V_{OUT1(NOM)} = 3.3V, V_{OUT2(NOM)} = 3.3V, Enable pins are tied to V_{IN} .



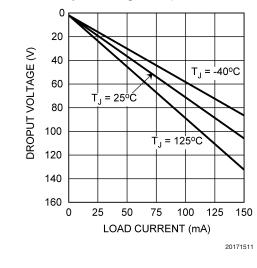




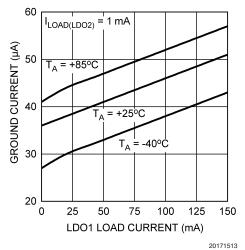
Ground Current vs Load Current, LDO2



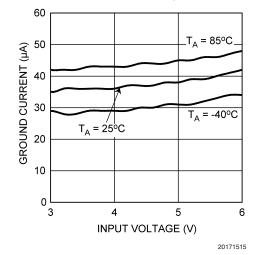
Dropout Voltage vs I_{LOAD} , LDO1



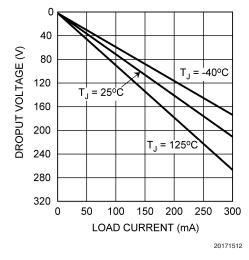




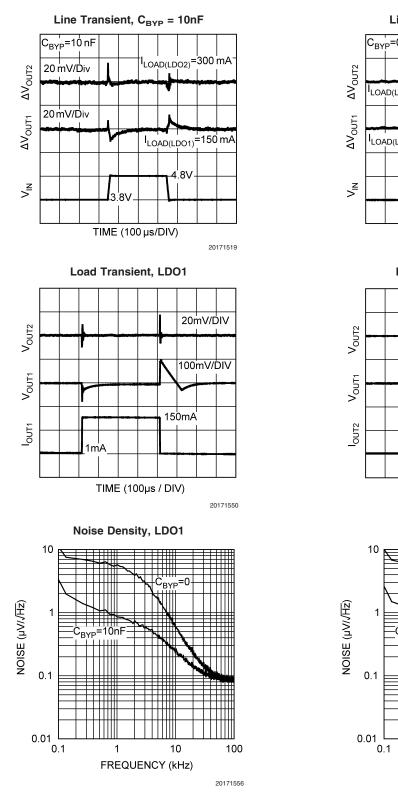
Ground Current vs V_{IN} , $I_{LOAD} = 1mA$

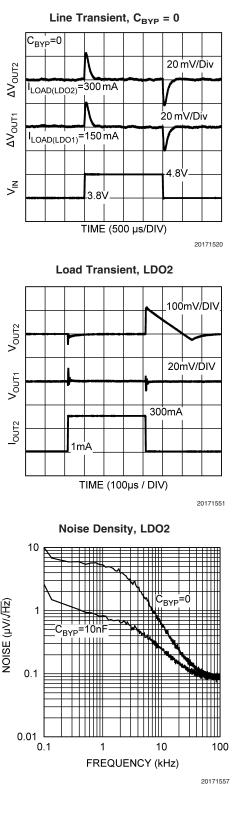


Dropout Voltage vs I_{LOAD}, LDO2



Typical Performance Characteristics. Unless otherwise specified, C_{IN} = 1.0µF Ceramic, C_{OUT1} = Co查询!!如好99660-4625="供应商_N = V_{OUT2(NOM)} + 1.0V, T_A = 25°C, V_{OUT1(NOM)} = 3.3V, V_{OUT2(NOM)} = 3.3V, Enable pins are tied to V_{IN}. (Continued)

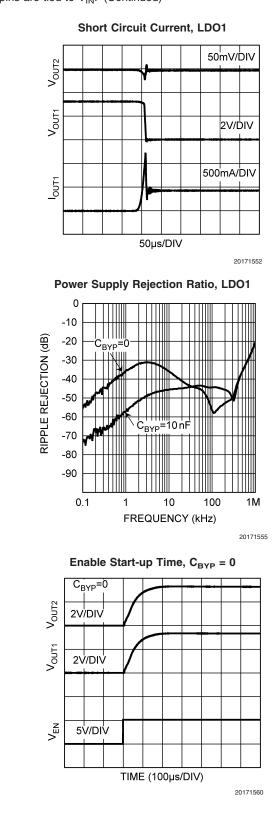


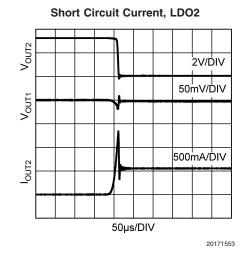




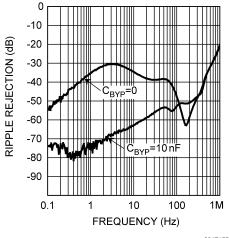
 Signal Performance Characteristics.
 Unless otherwise specified, C_{IN} = 1.0µF Ceramic, C_{OUT1} =

 算道『LR56968DµF162@州共応商 = 10nF, V_{IN} = V_{OUT2(NOM)} + 1.0V, T_A = 25°C, V_{OUT1(NOM)} = 3.3V, V_{OUT2(NOM)} = 3.3V, Enable pins are tied to V_{IN}. (Continued)



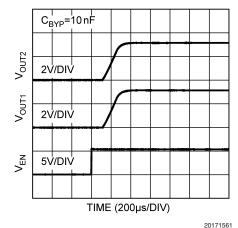


Power Supply Rejection Ratio, LDO2



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Enable Start-up Time, C_{BYP} = 10nF



Application Hints 查询"LP5996SD-1525"供应商 OPERATION DESCRIPTION

The LP5996 is a low quiescent current, power management IC, designed specifically for portable applications requiring minimum board space and smallest components. The LP5996 contains two independently selectable LDOs. The first is capable of sourcing 150mA at outputs between 0.8V and 3.3V. The second can source 300mA at an output voltage of 0.8V to 3.3V.

INPUT CAPACITOR

An input capacitor is required for stability. It is recommended that a 1.0μ F capacitor be connected between the LP5996 input pin and ground (this capacitance value may be increased without limit).

This capacitor must be located a distance of not more than 1cm from the input pin and returned to a clean analogue ground. Any good quality ceramic, tantalum, or film capacitor may be used at the input.

Important: Tantalum capacitors can suffer catastrophic failures due to surge current when connected to a lowimpedance source of power (like a battery or a very large capacitor). If a tantalum capacitor is used at the input, it must be guaranteed by the manufacturer to have a surge current rating sufficient for the application.

There are no requirements for the ESR (Equivalent Series Resistance) on the input capacitor, but tolerance and temperature coefficient must be considered when selecting the capacitor to ensure the capacitance will remain approximately 1.0μ F over the entire operating temperature range.

OUTPUT CAPACITOR

The LP5996 is designed specifically to work with very small ceramic output capacitors. A 1.0μ F ceramic capacitor (temperature types Z5U, Y5V or X7R) with ESR between 5m Ω to 500m Ω , is suitable in the LP5996 application circuit.

For this device the output capacitor should be connected between the $V_{\rm OUT}$ pin and ground.

It is also possible to use tantalum or film capacitors at the device output, C_{OUT} (or V_{OUT}), but these are not as attractive for reasons of size and cost (see the section Capacitor Characteristics).

The output capacitor must meet the requirement for the minimum value of capacitance and also have an ESR value that is within the range $5m\Omega$ to $500m\Omega$ for stability.

NO-LOAD STABILITY

The LP5996 will remain stable and in regulation with no external load. This is an important consideration in some circuits, for example CMOS RAM keep-alive applications.

CAPACITOR CHARACTERISTICS

The LP5996 is designed to work with ceramic capacitors on the output to take advantage of the benefits they offer. For capacitance values in the range of 0.47μ F to 4.7μ F, ceramic capacitors are the smallest, least expensive and have the lowest ESR values, thus making them best for eliminating high frequency noise. The ESR of a typical 1.0μ F ceramic capacitor is in the range of $20m\Omega$ to $40m\Omega$, which easily meets the ESR requirement for stability for the LP5996.

For both input and output capacitors, careful interpretation of the capacitor specification is required to ensure correct device operation. The capacitor value can change greatly, depending on the operating conditions and capacitor type.

In particular, the output capacitor selection should take account of all the capacitor parameters, to ensure that the specification is met within the application. The capacitance can vary with DC bias conditions as well as temperature and frequency of operation. Capacitor values will also show some decrease over time due to aging. The capacitor parameters are also dependant on the particular case size, with smaller sizes giving poorer performance figures in general. As an example, Figure 1 shows a typical graph comparing different capacitor case sizes in a Capacitance vs. DC Bias plot. As shown in the graph, increasing the DC Bias condition can result in the capacitance value falling below the minimum value given in the recommended capacitor specifications table (0.7µF in this case). Note that the graph shows the capacitance out of spec for the 0402 case size capacitor at higher bias voltages. It is therefore recommended that the capacitor manufacturers' specifications for the nominal value capacitor are consulted for all conditions, as some capacitor sizes (e.g. 0402) may not be suitable in the actual application.

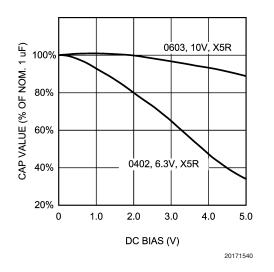


FIGURE 1. Graph Showing a Typical Variation in Capacitance vs DC Bias

The capacitance value of ceramic capacitors varies with temperature. The capacitor type X7R, which operates over a temperature range of -55°C to +125°C, will only vary the capacitance to within \pm 15%. The capacitor type X5R has a similar tolerance over a reduced temperature range of -55°C to +85°C. Many large value ceramic capacitors, larger than 1µF are manufactured with Z5U or Y5V temperature characteristics. Their capacitance can drop by more than 50% as the temperature varies from 25°C to 85°C. Therefore X7R is recommended over Z5U and Y5V in applications where the ambient temperature will change significantly above or below 25°C.

Tantalum capacitors are less desirable than ceramic for use as output capacitors because they are more expensive when comparing equivalent capacitance and voltage ratings in the 0.47μ F to 4.7μ F range.

Another important consideration is that tantalum capacitors have higher ESR values than equivalent size ceramics. This means that while it may be possible to find a tantalum

6 Application Hints (Continued) 查询"LP5996SD-1525"供应商 ithin the stable range, it would capacitor with an ESP value within the stable range, it would more costly) than a ceramic capacitor with the same ESR value. It should also be noted that the ESR of a typical tantalum will increase about 2:1 as the temperature goes from 25°C down to -40°C, so some guard band must be allowed.

ENABLE CONTROL

The LP5996 features active high enable pins for each regulator, EN1 and EN2, which turns the corresponding LDO off when pulled low. The device outputs are enabled when the enable pins are set to high. When not enabled the regulator output is off and the device typically consumes 2nA.

If the application does not require the Enable switching feature, one or both enable pins should be tied to V_{IN} to keep the regulator output permanently on.

To ensure proper operation, the signal source used to drive the enable inputs must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under VIL and VIH.

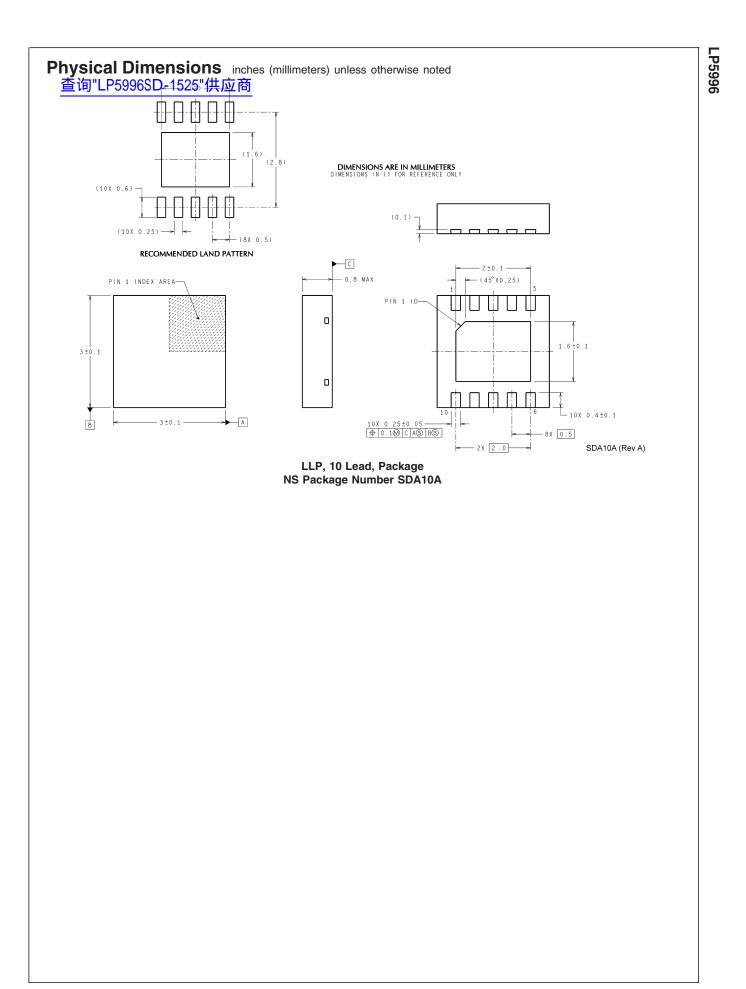
BYPASS CAPACITOR

The internal voltage reference circuit of the LP5996 is connected to the C_{BYP} pin via a high value internal resistor. An external capacitor, connected to this pin, forms a low-pass filter which reduces the noise level on both outputs of the device. There is also some improvement in PSSR and line transient performance. Internal circuitry ensures rapid charging of the C_{BYP} capacitor during start-up. A 10nF, high quality ceramic capacitor with either NPO or COG dielectric is recommended due to their low leakage characteristics and low noise performance.

SAFE AREA OF OPERATION

Due consideration should be given to operating conditions to avoid excessive thermal dissipation of the LP5996 or triggering its thermal shutdown circuit. When both outputs are power enabled. the total dissipation will be $P_{D(LDO1)} + P_{D(LDO2)}$ where PD = (V_{IN} - V_{OUT}) x I_{OUT} for each LDO

In general, device options which have a large difference in output voltage will dissipate more power with both outputs enabled, due to the input voltage required for the higher output voltage LDO. In such cases, especially at elevated ambient temperature, it may not be possible to operate both outputs at maximum current at the same time.



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